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# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet	1	of	1	Attorney Docket No.	TI-31089
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## Complete If Known

Application Number	09/876,292
Filing Date	08/07/01
First Named Inventor	Mahalingam Nandakumar, et al.
Group Art Unit	2815
Examiner Name	Edgardo Ortiz
Attorney Docket No.	TI-31089

## U.S. PATENT DOCUMENTS

Exam. Initials <sup>1</sup>	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			
EO	AA	5,023,878		Kinzer	6/11/01	
EO	AB	5,371,394		Ma et al.	12/6/04	
EO	AC	6,174,778		Chen et al.	1/16/01	
	AD					
	AE					
	AF					
	AG					
	AH					
	AI					
	AJ					
	AK					
	AL					

## FOREIGN PATENT DOCUMENTS

Exam. Initials <sup>1</sup>	Cite No. <sup>1</sup>	Foreign Patent Document			Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>3</sup>
		Office <sup>4</sup>	Number <sup>4</sup>	Kind Code <sup>2</sup> (if known)				
	BA	FR	2 798 204 A1		Aliou Jerome et al.	1/12/01		
	BB							
	BC							
	BD							
	BE							
	BF							
	BG							

## OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Exam. Initials <sup>1</sup>	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>3</sup>
EO	CA	KUNIKIYO TATSUYA, "Semiconductor Device and Its Manufacture" Patent Abstracts of Japan, Vol. 1995, No. 02, March 31, 1995, Publication Number 06318898, Publication Date November 15, 1994	
EO	CB	MORII TOMOYUKI, "MOS Type Semiconductor Device and Manufacture Thereof" Patent Abstracts of Japan, Vol. 014, No. 346, July 26, 1990, Publication Number 02119269, Publication Date May 7, 1990	
	CC		
	CD		
	CE		
	CF		
	CG		

Examiner Signature	<i>Edgardo Ortiz</i>	Date Considered	4/22/04
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